



# Structural phase purification of bulk HfO<sub>2</sub>:Y through pressure cycling

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We combine synchrotron-based infrared absorption and Raman scattering spectroscopies with diamond anvil cell techniques and first-principles calculations to explore the properties of hafnia under compression. We find that pressure drives HfO<sub>2</sub>:7%Y from the mixed monoclinic (*P*<sub>2</sub><sub>1</sub>/*c*) + antipolar orthorhombic (*Pbca*) phase to pure antipolar orthorhombic (*Pbca*) phase at approximately 6.3 GPa. This transformation is irreversible, meaning that upon release, the material is kinetically trapped in the *Pbca* metastable state at 300 K. Compression also drives polar orthorhombic (*Pca*<sub>2</sub><sub>1</sub>) hafnia into the tetragonal (*P*<sub>4</sub><sub>2</sub>/*nmc*) phase, although the latter is not metastable upon release. These results are unified by an analysis of the energy landscape. The fact that pressure allows us to stabilize targeted metastable structures with less Y stabilizer is important to preserving the flat phonon band physics of pure HfO<sub>2</sub>.

hafnia | phase purification | pressure cycling | competing phases | vibrational spectroscopies

The simple binary composition of hafnia (HfO<sub>2</sub>) belies a complex energy landscape with many competing phases (1). In addition to the monoclinic *P*<sub>2</sub><sub>1</sub>/*c* bulk ground state, other reported metastable phases include an antipolar orthorhombic *Pbca* phase and a polar orthorhombic *Pca*<sub>2</sub><sub>1</sub> phase. This presents both challenges and opportunities in realizing the properties of these materials for applications (2–8) and identifying pathways by which these phases can be reached is of great interest (9–12). In particular, the observation of ferroelectricity in thin films (13–16) and the prediction of flat bands and scalable ferroelectricity in the metastable polar orthorhombic phase of hafnia is generating high hopes for the prospect of single atom memory (17). Achieving the dream of atomically sharp domains acting as individually switchable dipoles (17) requires meeting the synthetic challenge for high-quality polar orthorhombic HfO<sub>2</sub> as a physical platform for such a device (1, 18).

Efforts to grow single crystals of ferroelectric HfO<sub>2</sub> have relied on high-temperature laser floating zone techniques, rapid temperature quenching, and use of Y as a stabilizer (19–22). Pressure represents another tool to navigate the complex energy landscapes and access metastable phases, with the best-known example being the development of synthetic diamond. Previous pressure studies of hafnia have focused on the phase sequence starting with the ambient monoclinic phase (23–32). Whether metastable phases of interest—particularly the ferroelectric and antipolar phases—can be accessed and potentially stabilized with pressure rather than temperature and then recovered to ambient conditions is currently underexplored. This type of analysis of phase stability is also relevant to thin films, although there, strain is a better control parameter.

In this work, we investigate pressure-induced phases and reversibility on release of pressure in HfO<sub>2</sub>:*x*%Y (*x* = 0, 7, 11, 12, 20), which under ambient conditions hosts, respectively, a monoclinic phase (*P*<sub>2</sub><sub>1</sub>/*c*), a mixed phase (*P*<sub>2</sub><sub>1</sub>/*c* + *Pbca*), an antipolar orthorhombic (*Pbca*) phase, a polar orthorhombic (*Pca*<sub>2</sub><sub>1</sub>) phase, and a cubic (*Fm*<sub>3</sub>*m*) phase (Fig. 1 and *SI Appendix, Table S1*) (20, 33). Previous efforts reveal that these phases can be identified by their vibrational fingerprints via a combination of synchrotron-based infrared absorption and Raman scattering combined with complementary lattice dynamics calculations (34, 35). This approach is successful because the irreducible representations of distinct crystal phases exhibit the full crystal symmetry. Here, we show that this approach can be extended to elevated pressures using diamond anvil cell techniques to identify different forms of the material under pressure cycling up to 27 GPa. For the majority of doping concentrations, our room temperature measurements show reversible pressure-induced structural changes which are in excellent agreement with predictions from our first-principles calculations. For instance, there is a reversible transition from the polar orthorhombic to the tetragonal phase at Y stabilizer concentrations that are significantly lower than what might be expected.

## Significance

In the last decade, the functional possibilities of metastable phases of HfO<sub>2</sub>, including the orthorhombic ferroelectric phase and the antipolar *Pbca* phase, have stimulated intense experimental and theoretical research effort. Synthesis of several of these phases as bulk single crystals has been achieved with ultra-high-temperatures and rapid quenching in combination with Y stabilizer concentrations of up to 20%. Here, we show how to access the antipolar phase and a theoretically predicted metastable tetragonal phase at room temperature using pressure cycling with reduced Y concentration, yielding samples closer to the ideal of pure HfO<sub>2</sub>.

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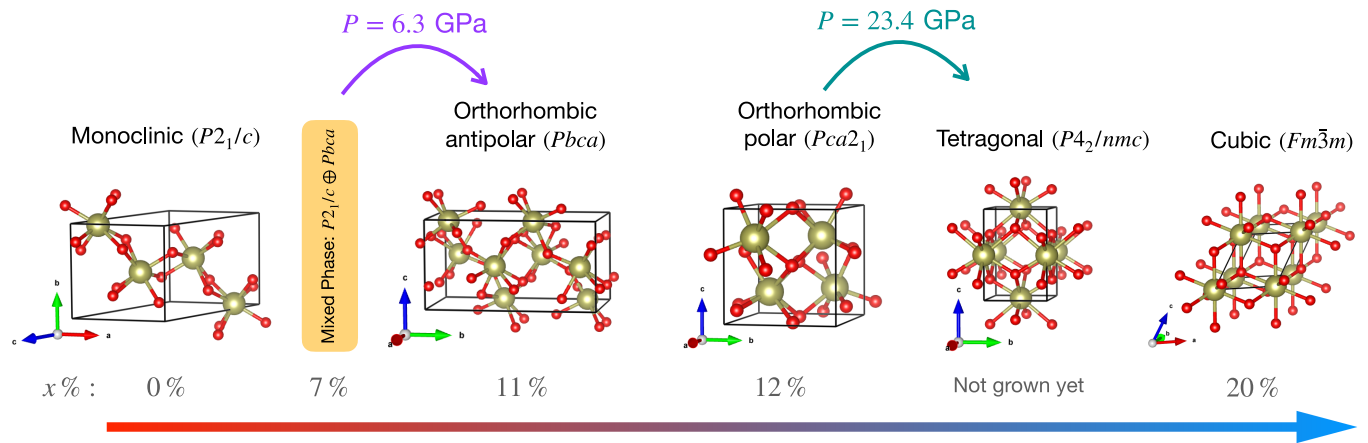
The authors declare no competing interest.

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**Fig. 1.** Summary of the various phases of hafnia of interest in this work, i.e., monoclinic HfO<sub>2</sub> (the ground state), and the higher-energy metastable phases arranged in the order of their increasing formation energy. When formed by laser floating zone + rapid cooling techniques (20), Y concentrations of 0, 7, 11, 12, and 20% yield monoclinic, mixed monoclinic and antipolar orthorhombic, antipolar orthorhombic, polar orthorhombic, and cubic phases, respectively. A metastable tetragonal phase has been predicted from first principles but not yet realized by these growth methods. X-ray scattering as well as TEM studies of the initial products of this study are available in ref. 20. The space groups are indicated above. The polar orthorhombic material is switchable (i.e., ferroelectric), whereas antipolar orthorhombic hafnia is not switchable (i.e., not antiferroelectric) (20). The curved arrows at the top indicate the pressure-induced transitions discussed in the text.

Moreover, for  $x = 7\%$ , we find that a mixed monoclinic + antipolar phase sample is converted to a pure antipolar phase at approximately 6.3 GPa. Remarkably, this transition is irreversible upon release, demonstrating that pressure cycling provides a route to clean, phase-pure materials. This work opens the door to the design of more complex protocols involving pressure cycling in conjunction with chemical stabilization that may ultimately provide a route to kinetic trapping of the sought-after ferroelectric orthorhombic phase of hafnia.

## Results and Discussion

**Pressure-Induced Mixed-to-Antipolar-Orthorhombic Transition in HfO<sub>2</sub>:7%Y.** Fig. 2A displays the Raman scattering response of HfO<sub>2</sub>:7%Y at ambient conditions. According to our X-ray analysis, this system hosts a mixed monoclinic (P<sub>21/c</sub>) + antipolar orthorhombic (P<sub>bca</sub>) structure (SI Appendix, Fig. S2). The Raman spectrum therefore contains phonons from both phases—a finding that we confirm by a comparison with complementary lattice dynamics calculations (Fig. 2A) (34). Most of the time, we would consider this to be an extremely low-quality “dirty” sample. As we show below, it turns out to be an excellent precursor to “clean” pure-phase materials.

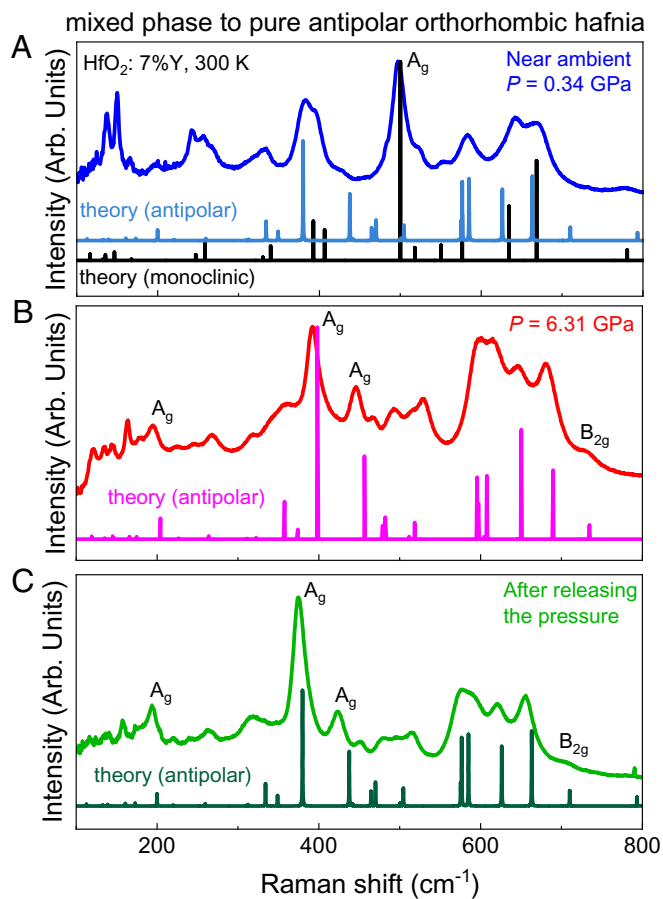
Fig. 2B shows the Raman scattering response of HfO<sub>2</sub>:7%Y under pressure. There is a clear structural phase transition from mixed phase (monoclinic + antipolar orthorhombic) to pure antipolar orthorhombic (P<sub>bca</sub>) structure at 6.3 GPa. This is interesting because it normally requires 11% Y stabilizer to trap the antipolar orthorhombic phase when prepared by laser floating zone + rapid cooling techniques (20). Strikingly, the mixed phase to pure antipolar orthorhombic transition is irreversible upon release of the pressure (Fig. 2C). In other words, a 6.3-GPa pressure cycle traps pure antipolar orthorhombic hafnia in a metastable state with only 7% Y doping—a reduction of 36%. The infrared response under pressure is consistent with these findings. We discuss the dirty to clean transition in terms of overall phase stability below.

We also investigated the stability of this pressure-cycled material. Specifically, we sought to test whether antipolar orthorhombic HfO<sub>2</sub>:7%Y is transient (reverting to a mixed

ground state over time) or a pure long-lived metastable state akin to diamond. Raman scattering spectroscopy reveals that antipolar orthorhombic HfO<sub>2</sub>:7%Y prepared in this manner is stable immediately after release, at the 5 d mark, and over more than four months. We therefore conclude that antipolar orthorhombic HfO<sub>2</sub>:7%Y is metastable indefinitely at room temperature. To further explore the stability of this material, we heated the sample to 200 °C in a vacuum oven and remeasured the Raman response. There are no new peaks in the Raman scattering spectrum, so we conclude that any barrier to reversal is much larger than  $k_B T = 200$  °C. These data are shown in SI Appendix.

**Antipolar Orthorhombic HfO<sub>2</sub>:7%Y at Higher Pressures.** Having established the mixed phase to pure antipolar orthorhombic transition in HfO<sub>2</sub>:7%Y at 6.3 GPa, we decided to continue compressing the sample to test whether the polar orthorhombic phase can be stabilized as well. While Raman scattering is the perfect technique to follow the mixed to antipolar transition as discussed above, we find that it is less useful at higher pressures because the sample starts to fluoresce—at least with a green laser. As a result, it is difficult to follow the phonons above approximately 20 GPa. We therefore turned to synchrotron-based far infrared spectroscopy to avoid the fluorescence and continue our search for evidence of the polar orthorhombic phase at pressures above 6.3 GPa.

Fig. 3 summarizes the synchrotron-based far-infrared response of HfO<sub>2</sub>:7%Y as a function of pressure at 300 K. There are several noticeable changes above 20 GPa including i) strengthening of the low-frequency structure near 100 cm<sup>-1</sup>, ii) formation of a weak feature near 225 cm<sup>-1</sup>, iii) red shifting of the edge near 380 cm<sup>-1</sup>, and iv) loss of structure near 540 cm<sup>-1</sup>. Despite these signatures, the spectral response of this material is not compatible with expectations for pure-phase polar orthorhombic hafnia (34). Instead, it corresponds to the antipolar orthorhombic phase (34). The system remains in the antipolar orthorhombic phase upon release—not the mixed state—identical to what we described above. We therefore see that compression of HfO<sub>2</sub>:7%Y provides a facile and reliable route to the antipolar orthorhombic phase. While this phase cannot be used for FeRAM devices, antiferroelectrics (switchable antipolar materials) are extremely



**Fig. 2.** (A) Raman scattering response of  $\text{HfO}_2:7\%Y$  at room temperature in a closed diamond anvil cell. This sample consists of mixed monoclinic + antipolar orthorhombic structures at 0.34 GPa. Theoretically calculated Raman spectra of the pure monoclinic ( $P2_1/c$ ) and antipolar orthorhombic ( $Pbca$ ) phases at zero pressure are plotted below the experimental data. (B) Raman scattering response of  $\text{HfO}_2:7\%Y$  at room temperature and  $P = 6.3$  GPa. The theoretical Raman spectrum of the antipolar orthorhombic ( $Pbca$ ) phase of hafnia at the same pressure is included below. (C) Raman scattering response of  $\text{HfO}_2:7\%Y$  at room temperature after release. As discussed in the main text, a pure antipolar orthorhombic ( $Pbca$ ) phase appears above 6.3 GPa which is trapped upon release of the pressure. The theoretical Raman spectrum at zero pressure is included as well. The symmetries of the signature modes are labeled for each phase (34). Note that there is additional symmetry breaking occurring in the experimental data due to Y stabilizer incorporation (34).

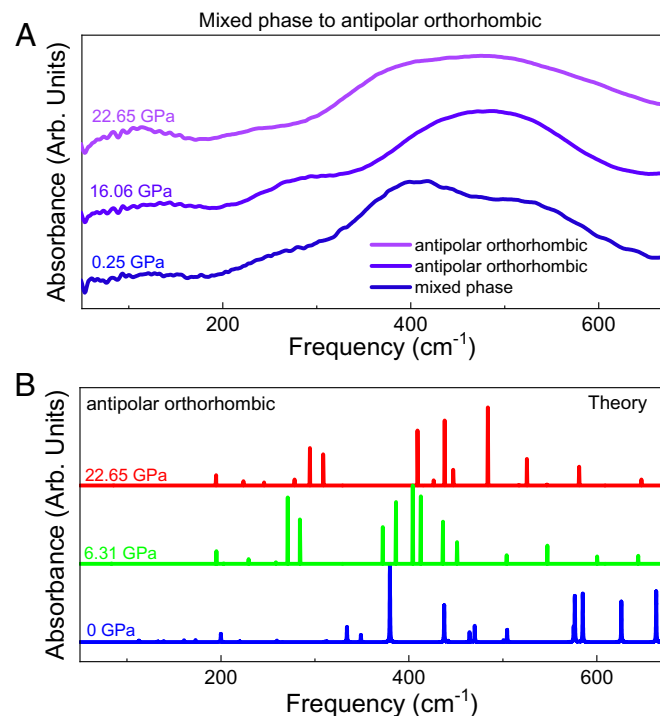
useful for energy storage applications (36). In combination with external stimuli like electric field, the antipolar form of  $\text{HfO}_2$  might function as a precursor to the polar phase and, at the same time, provide a platform for unraveling wake-up and fatigue processes (18, 37, 38).

**Antipolar Orthorhombic  $\text{HfO}_2:11\%Y$  under Pressure.** We also investigated  $\text{HfO}_2:11\%Y$  under compression to examine whether it could be driven into a polar orthorhombic phase with reduced stabilizer concentration. Measurements to 20 GPa did not clearly reveal a transition to the  $Pca2_1$  phase (SI Appendix, Fig. S3). The system is also fully reversible to the antipolar orthorhombic ( $Pbca$ ) form upon release to ambient pressure conditions. Analysis of the energy landscape, discussed below, demonstrates why this is so.

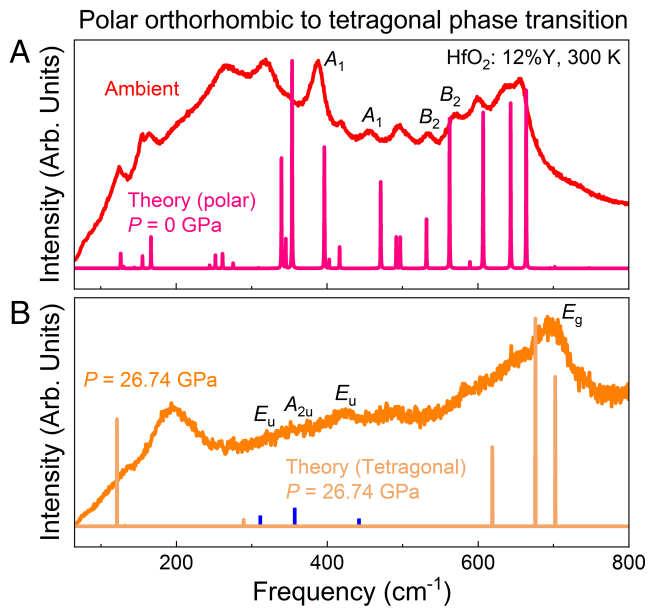
**Pressure-Driven Polar Orthorhombic to Tetragonal Phase Transition in  $\text{HfO}_2:12\%Y$ .** In addition to producing clean materials from mixed-phase samples, compression is an external stimulus

that can induce structural phase transitions and, via topotactic reaction, create new materials. A key example of such a process is the transformation from polar orthorhombic hafnia to the elusive tetragonal phase in  $\text{HfO}_2:12\%Y$ . We mention the polar orthorhombic to tetragonal transition here to emphasize that compression can also stabilize entirely new phases of hafnia with lower-than-anticipated Y concentrations—at least from the point of view of a laser floating zone + rapid cooling growth protocol (20). Fig. 4 displays the Raman scattering response of  $\text{HfO}_2:12\%Y$  at 0 and 26.74 GPa. The spectra under these conditions clearly correspond well to predictions for the various phonon modes in the polar orthorhombic ( $Pca2_1$ ) and tetragonal ( $P4_2/nmc$ ) phases (34). Even Y-induced defect modes in the high-pressure phase are beautifully predicted and observed. This process is reversible upon release, so the tetragonal phase is not kinetically trapped at room temperature. That said, it may be possible to develop an alternate pathway—perhaps using high-temperature-high pressure routes—to preserve this metastable state. Such an approach differs from using temperature alone to initiate conversion via grain boundary nucleation, which has been shown to yield a polycrystalline tetragonal phase in hafnia nanorods (39).

**Enthalpy vs. Pressure Phase Diagram of the Competing Phases of Hafnia.** In order to investigate the complex energy landscape and nature of the pressure-induced phase transitions, we performed first-principles density functional theory (DFT) calculations in pure-phase hafnia under pressure. This approach was selected based on our prior work (20), where we demonstrated, by conducting comprehensive DFT calculations on  $Y:\text{HfO}_2$

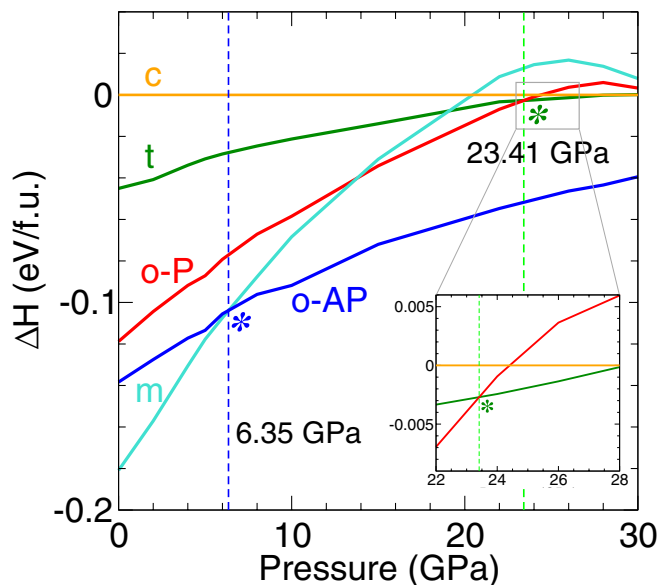


**Fig. 3.** (A) Synchrotron-based infrared absorbance of mixed-phase  $\text{HfO}_2:7\%Y$  as a function of pressure. The antipolar orthorhombic ( $Pbca$ ) phase is formed under compression. Pressures up to 22.65 GPa do not yield the polar orthorhombic phase—at least not in a straightforward manner at room temperature. We also do not see evidence for the cotunnite phases (28), probably due to the presence of Y stabilizer. The spectra are offset for clarity. (B) Calculated mode patterns of antipolar orthorhombic ( $Pbca$ ) hafnia at different pressures for comparison.



**Fig. 4.** (A) Raman scattering response of  $\text{HfO}_2:12\%Y$  at ambient conditions compared with the results of our lattice dynamics calculations. The symmetries of the signature modes for polar orthorhombic hafnia are labeled. (B) Compression drives a transition from the polar orthorhombic ( $Pca2_1$ ) to the tetragonal ( $P4_2/nmc$ ) phase. The theoretically calculated Raman spectrum of tetragonal hafnia is shown for comparison. In addition to the fundamental excitations of the lattice associated with each phase, there is evidence for additional features (shown in blue) that we assign as infrared-active modes appearing due to symmetry breaking induced by Y substitution (34). Based upon the peak shapes, the sample is still in single crystal form at 26.74 GPa.

supercells, that small Y concentrations do not substantially alter the relative formation energy of the various  $\text{HfO}_2$  phases. We find that at zero pressure the ground state phase of hafnia is monoclinic (m), followed by orthorhombic antipolar (o-AP), orthorhombic polar (o-P), tetragonal (t), and cubic (c) phases, in the order



**Fig. 5.** Enthalpy ( $\Delta H$ ) vs. pressure diagram of the five competing phases of hafnia i.e., cubic (c), tetragonal (t), orthorhombic polar (o-P), orthorhombic antipolar (o-AP), and monoclinic (m), calculated with respect to the cubic phase. Blue and green vertical dashed lines at 6.35 and 23.41 GPa mark the critical pressure where phase transitions are predicted to occur. The *Inset* shows an enlarged view near 23 GPa.

of increasing energy. Our calculated enthalpy vs. pressure phase diagram, shown in Fig. 5, reveals that the orthorhombic antipolar phase becomes the ground state above a critical pressure of 6.35 GPa. This is in remarkable agreement with our experimentally observed phase transition of the mixed monoclinic + orthorhombic antipolar phase sample ( $\text{HfO}_2:7\%Y$ ) to the pure orthorhombic antipolar phase at 6.3 GPa (Fig. 2). There is another structural phase transition of interest near 23.4 GPa. Above this critical pressure, the tetragonal phase becomes lower in enthalpy compared to the orthorhombic polar phase implying a possible phase transition from the orthorhombic polar phase to the tetragonal phase. This explains why the orthorhombic polar phase sample ( $\text{HfO}_2:12\%Y$ ) transforms into the tetragonal phase above 22 GPa (Fig. 4). Interestingly, tetragonal distortions are predicted to be subtle at pressures above 28 GPa, and tetragonal and cubic phases become almost indistinguishable.

Upon pressure release,  $\text{HfO}_2:12\%Y$  transforms back to the orthorhombic polar phase since it has substantially lower enthalpy compared to the tetragonal phase. On the other hand,  $\text{HfO}_2:7\%Y$  is kinetically trapped in the pure orthorhombic antipolar phase even when pressure is released. This is due to the fact that monoclinic and orthorhombic antipolar phases have competing enthalpies at lower pressures, which makes kinetic trapping possible using our crystal growth technique (i.e., Y substitution and rapid cooling) (20). Under the normal bulk hafnia crystal growth conditions, i.e., no Y substitution and no rapid cooling, the orthorhombic antipolar phase should convert into a monoclinic phase below 6.3 GPa and vice versa (Fig. 5).

## Conclusions

Thus far, we measured the vibrational properties of  $\text{HfO}_2:x\%Y$  ( $x = 7, 11, 12$ ) under compression in order to explore pressure cycling as a route to pure and elusive phases of hafnia. We tested several different pressure pathways as part of this work and found that two types of processes are enabled: developing pure-phase antipolar hafnia from a mixed-phase sample and creating the tetragonal form from the polar orthorhombic material. Pressure cycling is thus a route to high quality as well as more interesting materials. Some of these phases are metastable and do not anneal back to their original state at 300 K. We also point out that pressures like 6 or 20 GPa are minimal compared to 3,300 °C (the temperature for laser floating zone growth of these materials), and high pressure–high-temperature techniques are used routinely in the manufacture of lab-grown diamonds. The ability to employ a room temperature pressure cycle to replace Y stabilizer also has important advantages for flat band preservation, moving us a step closer to realizing the full potential of scale-free ferroelectricity in useful FeRAM devices as well as antiferroelectricity in energy storage applications. Going forward, it will be helpful to explore these effects by X-ray techniques. Our analysis of phase stability in the hafnia system suggests that pressure by itself will not be enough to drive the system into the polar orthorhombic phase. Combined pressure–temperature routes are therefore of future interest. Small strains or nano-sizing may induce similar effects.

## Materials and Methods

**Crystal Growth and Sample Preparation.** High-quality single crystals of hafnia stabilized with yttrium (chemical formula  $\text{HfO}_2:x\%Y$ ;  $x = 0, 7, 11, 12, 20$ ) were grown by laser-diode heated floating zone techniques with rapid cooling as described previously (20). X-ray scattering and TEM images of the materials prepared by this technique are available in ref. 20 as well. This series of materials is summarized in Fig. 1. A small, well-shaped piece of the mixed-

phase material (HfO<sub>2</sub>:7%Y) was loaded into a diamond anvil cell equipped with either type IIas or ultra-low fluorescence diamonds. We also studied antipolar orthorhombic HfO<sub>2</sub>:11%Y and polar orthorhombic HfO<sub>2</sub>:12%Y to a lesser extent. The samples were loaded into diamond anvil cells in the same manner. The diamonds had 400 μm culets, and we employed a pre-indented stainless steel gasket with a 200 μm gasket hole. We used either petroleum jelly or KBr as a pressure medium (depending on the measurement) to assure quasi-hydrostatic pressure conditions. An annealed ruby ball was used to determine pressure via fluorescence (40, 41). We monitor the shape of the ruby fluorescence spectrum to assure that the sample remains in a quasi-hydrostatic environment (*SI Appendix, Fig. S1*). Both the infrared and Raman scattering responses show some orientational dependence that varies from load to load. For the infrared load, the optical density was optimized for significant but non-saturating absorption in order to reveal the features of interest. Annealing tests were carried out in a simple vacuum oven.

**Infrared Absorbance and Raman Scattering Measurements.** Taking advantage of the stable, high-brightness beam, synchrotron-based infrared spectroscopy (60 to 680 cm<sup>-1</sup>; 4 cm<sup>-1</sup> resolution; transmittance geometry) was performed using a Bruker Vertex 80 equipped with a bolometer detector at the 22-IR-1 beamline at the National Synchrotron Light Source II at Brookhaven National Laboratory. Absorbance was calculated as  $\alpha(\omega) = -\ln(\mathcal{T}(\omega))$ , where  $\mathcal{T}(\omega)$  is the measured transmittance. We employed a fast Fourier transform to remove fringes in the data (from the diamond anvil cell and due to the thinness of the sample). Raman scattering was carried out using a single grating system with a 500-mm focal length, a 20× objective with a 30-mm working distance, a 532-nm laser ( $\leq 2$  mW with a defocused beam), an 1,800-line/mm grating, and a liquid N<sub>2</sub>-cooled CCD detector. Spectra were collected for 60 s and averaged 10 times. Pressure was increased between 0 and approximately 25 GPa at room temperature. Sample fluorescence increased significantly at higher pressures, and when that happened, we did not go further. In these cases, infrared spectroscopy was the superior probe. The pressure cycling pathways that we employed are described in the main text. As a reminder, vibrational spectroscopies are incredibly sensitive to symmetry—especially in combination with first principles theory as demonstrated here—providing very specific information on the phases that arise under pressure (34). In any case, we find that the majority of phase transitions are reversible upon release of pressure, although some are irreversible. We discuss these findings in the spirit of highlighting both opportunities and limitations of this pressure cycling technique.

**First-Principles Calculations.** All the reported DFT calculations were performed using the Vienna Ab initio Simulation Package (VASP) (42–44) within the projector-augmented wave framework (45). The structural parameters for

these materials are summarized in *SI Appendix, Table S1*. The generalized-gradient approximation as parameterized by Perdew, Burke, and Ernzerhof (PBEsol) was employed for the exchange-correlation functional (46). The total energy convergence and residual force convergence criteria were set to 10<sup>-7</sup> eV and 10<sup>-3</sup> eV/Å. We used a Monkhorst-Pack *k*-mesh (47) of size 8 × 8 × 8, 12 × 12 × 8, 8 × 8 × 8, 8 × 8 × 4, and 8 × 8 × 6 to sample the reciprocal space of cubic (c), tetragonal (t), orthorhombic polar (o-P), orthorhombic antipolar (o-AP), and monoclinic (m) phases, respectively. Theoretical infrared and Raman spectra were computed using the zone-center phonon eigenvectors and eigenfrequencies (34, 48). The Bilbao Crystallographic Server (49) and phonopy package (50) were utilized to determine the Raman selection rules and symmetry of the phonon eigenvectors.

**Data, Materials, and Software Availability.** All study data are included in the article and/or *SI Appendix*.

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